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RESEARCH REPORT
NIFS Series

Physical Model of Nernst Element

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Abstract

Generation of electric power by the Nernst effect is a new application of a semiconductor. A key point of this proposal is to find materials with a high thermomagnetic figure-of-merit, which are called Nernst elements. In order to find candidates of the Nernst element, a physical model to describe its transport phenomena is needed. As the first model, we began with a parabolic two-band model in classical statistics. According to this model, we selected InSb as candidates of the Nernst element and measured their transport coefficients in magnetic fields up to 4 Tesla within a temperature region from 270K to 330K. In this region, we calculated transport coefficients numerically by our physical model. For InSb, experimental data are coincident with theoretical values in strong magnetic field.

Keywords: indium antimonide, two band model, Nernst effect, power generation, strong magnetic field, transport coefficient, Boltzmann equation, temperature gradient

1 Introduction

One of the authors, S. Y., proposed [1] the direct electric energy conversion of the heat from plasma by the Nernst effect in a fusion reactor, where a strong magnetic field is used to confine a high temperature fusion plasma. He called [1, 2] the element which induces the electric field in the presence of temperature gradient and magnetic field, as Nernst element. In his papers [1, 2], he also estimated the figure of merit of the Nernst element in a semiconductor model. In his results [1, 2], the Nernst element has high performance in low temperature region, that is, 300 – 500 K. Before his works, the Nernst element was studied in the 1960's [3]. In those days, induction of the magnetic field had a lot of loss of energy. This is the reason why the Nernst element cannot be used. Nowadays an improvement on superconducting magnet gives us higher efficiency of the induction of the strong magnetic field. We started a measuring system of transport coefficients in the strong magnetic field to estimate efficiency of the Nernst element on a few years ago [4]. We need criteria to find materials with high efficiency. The first model is one-band model which was proposed by S. Y. [1] However his model cannot explain the temperature dependence of the Nernst coefficient above the room temperature for intrinsic indium antimonide, InSb_X [4, 5]. We improved the one-band model to the two-band model. In this paper, we measured InSb_B which is doped Te heavier than InSb_X. Near room temperature, the sample InSb_B transits from the extrinsic region to the intrinsic region. To calculate transport coefficients

of InSb_B in a magnetic field, we use the two-band model, In this paper, we report the calculations by the two-band model. (In Ref. [6], we also measured and calculated transport coefficients of Ge in a magnetic field near room temperature.)

2 Theoretical calculations

As the physical model to describe transport phenomena of the material in the Nernst element, we use a parabolic two-band model in the classical statics. We have the following parameters of this model;

- m_n (m_p): effective mass of electron (hole),
- ε_D (ε_A): energy level of a donor (an acceptor),
- N_D (N_A): concentration of donors (acceptors),
- μ_n (μ_p): mobility of an electron (a hole),
- ε_G : energy gap, ε_F : fermi energy.

Using these parameters, we obtain concentrations of carriers as follows:

$$n(T) = N_C(T) \exp\left(\frac{\varepsilon_F - \varepsilon_G}{kT}\right), \quad (1)$$

$$p(T) = N_V(T) \exp\left(\frac{-\varepsilon_F}{kT}\right), \quad (2)$$

where $n(p)$ is the concentration of free electron (hole). Here N_C (N_V), the effective density of state in the conduction (valence) band is given by

$$N_C(T) = 2 \left(\frac{m_n kT}{2\pi\hbar^2}\right)^{3/2}, \quad (3)$$

$$N_V(T) = 2 \left(\frac{m_p kT}{2\pi\hbar^2}\right)^{3/2}, \quad (4)$$

where h is Planck's constant, $\hbar \equiv h/2\pi$, and k is Boltzmann's constant. We also obtain the concentration of electrons (holes) in the donor (acceptor) level, n_D (p_A) as follows:

$$n_D = N_D \frac{1}{1 + \frac{1}{2} \exp\left(-\frac{\varepsilon_D - \varepsilon_G + \varepsilon_F}{kT}\right)}, \quad (5)$$

$$p_A = N_A \frac{1}{1 + 2 \exp\left(-\frac{\varepsilon_A - \varepsilon_F}{kT}\right)}. \quad (6)$$

We suppose the charge neutrality as

$$N_D - n_D + p(T) = N_A - p_A(T) + n(T). \quad (7)$$

Substituting the concentrations of carriers with eqs. (1)-(6) in eq. (7), we obtain the following algebraic equation in value $x \equiv \exp(\varepsilon_F/kT)$ as

$$sux^4 + (u + N_A s + stu)x^3 + (N_A - N_D + ut - N_V s)x^2 - (N_D t + N_V + N_D st)x - N_V t = 0, \quad (8)$$

where

$$\begin{aligned} s &= 2 \exp\left(\frac{\varepsilon_D - \varepsilon_G}{kT}\right), \\ t &= \frac{1}{2} \exp\left(\frac{\varepsilon_A}{kT}\right), \\ u &= N_C \exp\left(-\frac{\varepsilon_G}{kT}\right). \end{aligned} \quad (9)$$

Using the fermi energy which is given from eqs. (8) and (9), we can solve the Boltzmann equation of this model in a magnetic field with a perturbation theory and the relaxation time approximation. See Ref. [1] for details. Here we define the following parameters to simplify formulation as

$$\eta \equiv \frac{\varepsilon_A}{kT}, \gamma = \frac{2m_n kT}{\hbar^2}, \beta_0 = \frac{\sqrt{\pi} \mu_n B}{4z}, \beta = \frac{\beta_0}{4} \gamma^{\frac{5}{2}}. \quad (10)$$

We also define the following integrals as

$$I_i(\beta_0) = 4\gamma^{-1} \int_0^\infty \frac{x^i \exp(\eta - x)}{1 + \frac{\beta_0^2}{x}} dx, \quad (11)$$

$$J_j(\beta_0) = 16\gamma^{-\frac{7}{2}} \int_0^\infty \frac{x^{j-\frac{1}{2}} \exp(\eta - x)}{1 + \frac{\beta_0^2}{x}} dx. \quad (12)$$

Using the above eqs. (10) - (12), we obtain transport coefficients in a magnetic field B , as follows:

$$\sigma(B) = \sigma(0) \frac{I_1^2 + (\beta J_1)^2}{I_1(0)I_1}, \quad \sigma(0) = en\mu_n, \quad (13)$$

$$R_H(B) = \frac{3\pi^2}{zen} \frac{nJ_1}{I_1^2 + (\beta J_1)^2}, \quad (14)$$

$$\alpha(B) = \frac{k}{ze} \left\{ \frac{I_1 I_2 + \beta^2 J_1 J_2}{I_1^2 + (\beta J_1)^2} \right\}, \quad (15)$$

$$\beta(B) \equiv N(B)B = \frac{k\beta}{ze} \left\{ \frac{J_1 I_2 - I_1 J_2}{I_1^2 + (\beta J_1)^2} \right\}, \quad (16)$$

where σ is the conductivity, R_H the Hall coefficient, α the thermoelectric power, and N the Nernst coefficient for electron ($z = -1$). For hole ($z = 1$), we must use p , $\eta + \varepsilon_G$, and μ_p instead of n , μ_n and η . Relations between these one-band transport coefficients and the two-band ones are written as [7]

$$\sigma = \frac{D}{\sigma_1(1 + B^2 R_{H2}^2 \sigma_2^2) + \sigma_2(1 + B^2 R_{H1}^2 \sigma_1^2)}, \quad (17)$$

$$\begin{aligned} R_H &= \frac{1}{D} \\ &\times \{ R_{H1} \sigma_1^2 + R_{H2} \sigma_2^2 + B^2 R_{H1} R_{H2} \sigma_1^2 \sigma_2^2 (R_{H1} + R_{H2}) \}, \end{aligned} \quad (18)$$

$$\begin{aligned} \alpha &= \frac{1}{D} \\ &\times \left\{ \begin{aligned} &\alpha_1 \{ \sigma_1 (\sigma_1 + \sigma_2) + \sigma_1^2 \sigma_2^2 R_{H2} (R_{H1} + R_{H2}) B^2 \} \\ &\alpha_2 \{ \sigma_2 (\sigma_1 + \sigma_2) + \sigma_1^2 \sigma_2^2 R_{H1} (R_{H1} + R_{H2}) B^2 \} \\ &+ \sigma_1 \sigma_2 (N_1 - N_2) (R_{H1} \sigma_1 - R_{H2} \sigma_2) B^2 \} \end{aligned} \right\}, \end{aligned} \quad (19)$$

$$\begin{aligned} N &= \frac{1}{D} \\ &\times \left\{ \begin{aligned} &N_1 \{ \sigma_1 (\sigma_1 + \sigma_2) + \sigma_1^2 \sigma_2^2 R_{H2} (R_{H1} + R_{H2}) B^2 \} \\ &N_2 \{ \sigma_2 (\sigma_1 + \sigma_2) + \sigma_1^2 \sigma_2^2 R_{H1} (R_{H1} + R_{H2}) B^2 \} \\ &+ \sigma_1 \sigma_2 (\alpha_1 - \alpha_2) (R_{H1} \sigma_1 - R_{H2} \sigma_2) \} \end{aligned} \right\}, \end{aligned} \quad (20)$$

where the subscripts 1 and 2 denote the contribution from conduction and valence bands, respectively. The parameter D is described as

$$D \equiv (\sigma_1 + \sigma_2)^2 + B^2 \sigma_1^2 \sigma_2^2 (R_{H1} + R_{H2})^2. \quad (21)$$

By the above algorithm, we calculate the transport coefficients in a magnetic field. In this calculations, we must prepare physical quantities i.e. effective masses, energy levels, concentrations of impurities, mobilities and energy gap. From the previous works [8], we can get the following parameters:

$$\begin{aligned} m_n &= 0.0152m_0, \\ m_p &= 1.1140m_0, \\ \varepsilon_G &= 0.210\text{eV}, \\ \varepsilon_D &= 0.0007\text{eV}, \\ \varepsilon_A &= 0.002\text{eV}, \\ \mu_n &= 38000T^{-1.5}\text{m}^2/\text{V/s}, \\ \mu_p &= 1056.86T^{-1.7}\text{m}^2/\text{V/s}, \\ N_D &= 2.1 \times 10^{22}\text{m}^{-3}, \\ N_A &= 0, \end{aligned} \quad (22)$$

where m_0 is the bare electron mass. Using eq. (22), we calculate transport coefficients.

3 Comparison between experimental and theoretical results

We measured transport coefficients of indium antimonide in a magnetic field. The sample X has the electron carrier concentration $n = 6.6 \times 10^{20}\text{m}^{-3}$ and mobility $\mu_n = 21\text{m}^2/\text{V/s}$ at 77K. The sample B has $n = 2.1 \times 10^{22}\text{m}^{-3}$ at 77K.

The conductivity and the Hall coefficient are measured by the van der Pauw method. The thermoelectric power and the Nernst coefficient are also measured for the bridge shaped sample [8]. In Fig. 1, we plot the thermoelectric power of InSb_X as a function of magnetic field. The Nernst coefficient of InSb_X is plotted in Fig. 2. These figures show that these transport coefficients can be calculated by the two-band model. For InSb_B, we also measured the conductivity, the Hall coefficient, the thermoelectric power and the Nernst coefficient. These results are plotted in Figs. 3-6. These transport coefficients given by the theoretical calculations coincide with the experimental values.

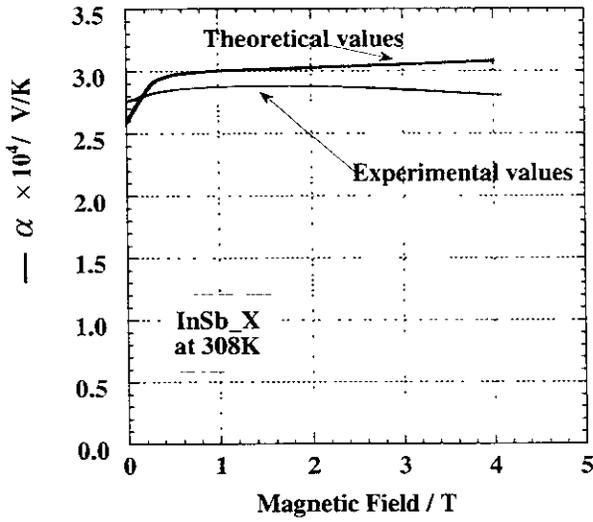


Figure 1: Thermoelectric power versus magnetic field of InSb_X at 308K

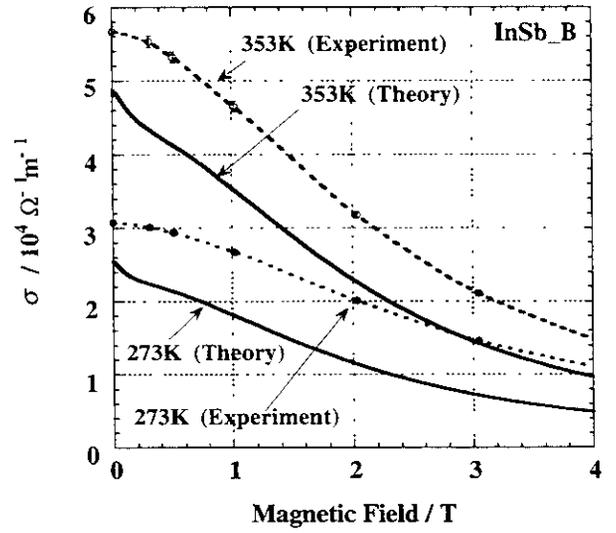


Figure 3: Electrical conductivity versus magnetic field of InSb_B at 273K and 353K

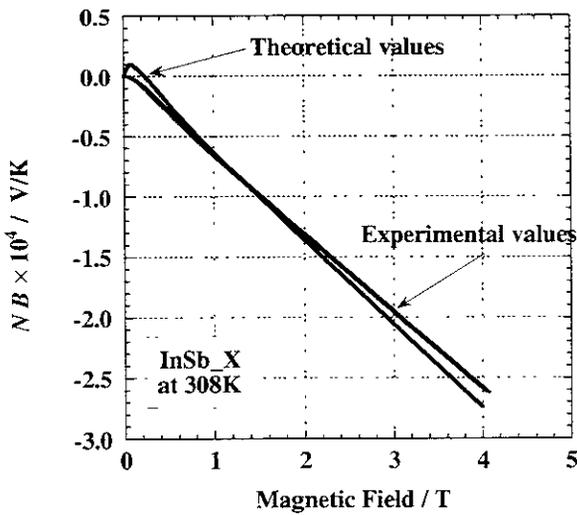


Figure 2: Nernst Coefficient multiplied by magnetic field NB versus magnetic field of InSb_X at 308K

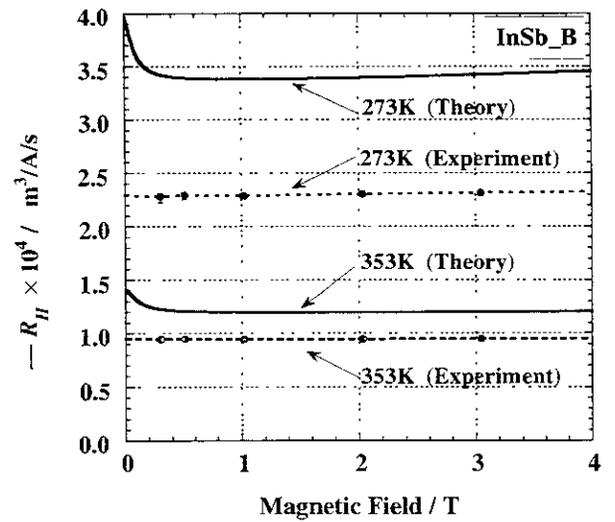


Figure 4: Hall coefficient versus magnetic field of InSb_B at 273K and 353K

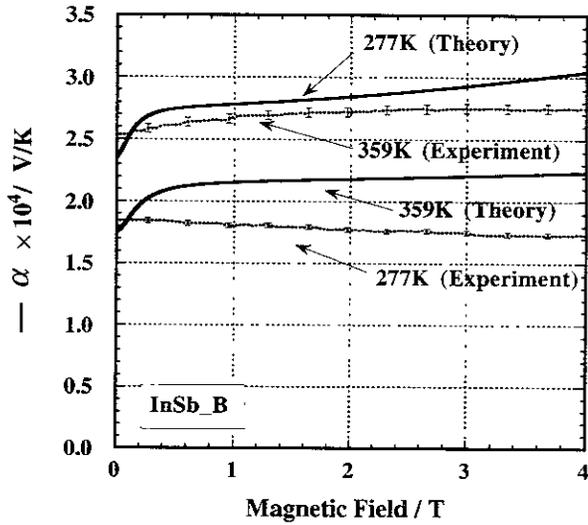


Figure 5: Thermoelectric power versus magnetic field of InSb_B at 273K and 353K

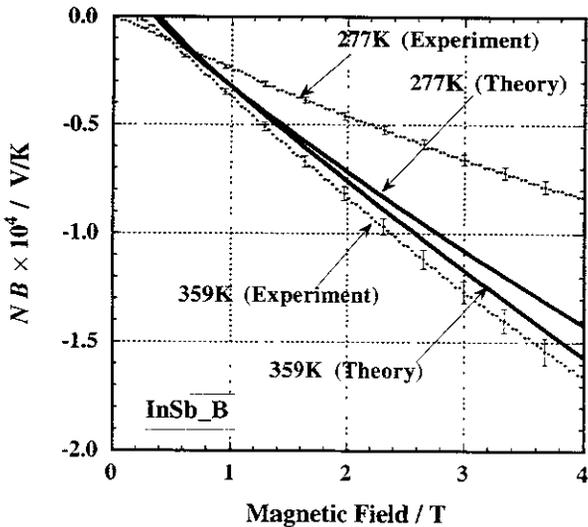


Figure 6: Nernst coefficient multiplied by magnetic field NB , versus magnetic field of InSb_B at 273K and 353K

4 Discussion and conclusions

From comparison between the experimental and the theoretical values, we conclude that the two-band model is an enough good model to estimate the transport coefficient. We need to measure thermal conductivity to estimate the thermomagnetic (i.e. Nernst) figure-of-merit $Z_N = \sigma(NB)^2/\kappa$. The thermal conductivity has phonon scattering mechanism. We, therefore, improve the physical model to include the phonon scattering phenomena. This is a future problem.

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